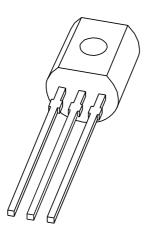
DISCRETE SEMICONDUCTORS

DATA SHEET



MPSA44 NPN high-voltage transistor

Product specification Supersedes data of 1999 Apr 27 2004 Oct 11





NPN high-voltage transistor

MPSA44

FEATURES

- Low current (max. 300 mA)
- High voltage (max. 400 V).

APPLICATIONS

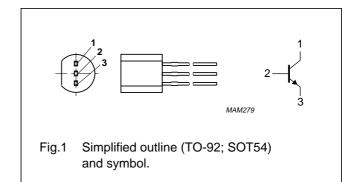
• Telecommunication applications.

DESCRIPTION

NPN high-voltage transistor in a TO-92; SOT54 plastic package.

PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | collector |
| 2 | base |
| 3 | emitter |



ORDERING INFORMATION

| TYPE NUMBER | | PACKAGE | |
|--------------|--------|---|---------|
| ITPE NOWIBER | NAME | DESCRIPTION | VERSION |
| MPSA44 | SC-43A | plastic single-ended leaded (through hole) package; 3 leads | SOT54 |

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|---------------------------|----------------------------------|------|------|------|
| V _{CBO} | collector-base voltage | open emitter | _ | 500 | V |
| V _{CEO} | collector-emitter voltage | open base | _ | 400 | V |
| V _{EBO} | emitter-base voltage | open collector | _ | 6 | V |
| I _C | collector current (DC) | | _ | 300 | mA |
| I _{CM} | peak collector current | | _ | 600 | mA |
| I _{BM} | peak base current | | _ | 100 | mA |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C; note 1 | _ | 625 | mW |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| T _j | junction temperature | | _ | 150 | °C |
| T _{amb} | ambient temperature | | -65 | +150 | °C |

Note

1. Transistor mounted on an FR4 printed-circuit board.

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THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|----------------------|---|------------|-------|------|
| R _{th(j-a)} | thermal resistance from junction to ambient | note 1 | 200 | K/W |

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|--------------------|--------------------------------------|---|------|------|------|
| I _{CBO} | collector-base cut-off current | V _{CB} = 400 V; I _E = 0 A | _ | 100 | nA |
| | | $V_{CB} = 400 \text{ V}; I_E = 0 \text{ A}; T_j = 150 ^{\circ}\text{C}$ | _ | 10 | μΑ |
| I _{EBO} | emitter-base cut-off current | V _{EB} = 4 V; I _C = 0 A | _ | 100 | nA |
| h _{FE} | DC current gain | V _{CE} = 10 V; I _C = 1 mA | 40 | _ | |
| | | $V_{CE} = 10 \text{ V}; I_{C} = 10 \text{ mA}$ | 50 | 200 | |
| | | V _{CE} = 10 V; I _C = 50 mA; note 1 | 45 | _ | |
| | | V _{CE} = 10 V; I _C = 100 mA; note 1 | 40 | _ | |
| V _{CEsat} | collector-emitter saturation voltage | I _C = 1 mA; I _B = 0.1 mA | _ | 400 | mV |
| | | $I_C = 10 \text{ mA}; I_B = 1 \text{ mA}$ | _ | 500 | mV |
| | | $I_C = 50 \text{ mA}; I_B = 5 \text{ mA}; \text{ note 1}$ | _ | 750 | mV |
| V _{BEsat} | base-emitter saturation voltage | I _C = 10 mA; I _B = 1 mA; note 1 | _ | 850 | mV |
| C _c | collector capacitance | $V_{CB} = 20 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}$ | _ | 7 | pF |
| C _e | emitter capacitance | $V_{EB} = 0.5 \text{ V}; I_C = I_C = 0 \text{ A}; f = 1 \text{ MHz}$ | _ | 180 | pF |
| f _T | transition frequency | V _{CE} = 10 V; I _C = 10 mA; f = 100 MHz | 20 | _ | MHz |

Note

1. Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

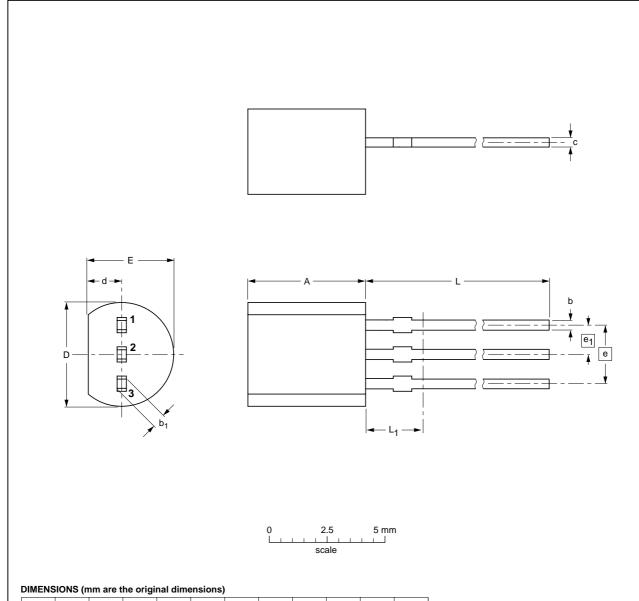
NPN high-voltage transistor

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PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



| UNIT | A | b | b ₁ | С | D | d | E | е | e ₁ | L | L ₁ ⁽¹⁾ max. | |
|------|------------|--------------|----------------|--------------|------------|------------|------------|------|----------------|--------------|---------------------------------------|--|
| mm | 5.2 5.0 | 0.48 0.40 | 0.66 0.55 | 0.45 0.38 | 4.8 4.4 | 1.7 1.4 | 4.2 3.6 | 2.54 | 1.27 | 14.5 12.7 | 2.5 | |

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

| OUTLINE | OUTLINE REFERENCES | | | | | ISSUE DATE |
|---------|--------------------|-------|--------|--|----------------|---------------------------------|
| VERSION | IEC | JEDEC | JEITA | | PROJECTION 155 | |
| SOT54 | | TO-92 | SC-43A | | | 97-02-28 04-06-28 |

NPN high-voltage transistor

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DATA SHEET STATUS

| LEVEL | DATA SHEET STATUS ⁽¹⁾ | PRODUCT STATUS(2)(3) | DEFINITION |
|-------|-------------------------------------|-------------------------|--|
| I | Objective data | Development | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice. |
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